

N-Channel 40 V (D-S) MOSFET

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (mΩ) (TYP.)	I _D (A) ^{a,e}	Q _g (TYP.)
40	0.58 at V _{GS} = 10 V	240	97 nC

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested

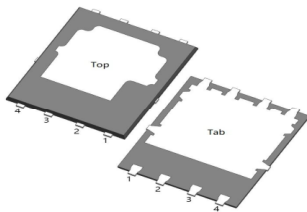


RoHS
COMPLIANT

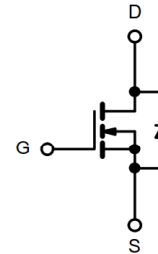
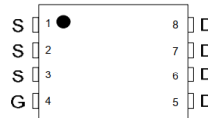
APPLICATIONS

- Notebook PC Core
- VRM/POL

DFN5*6 Double Cooling



Top View



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	40	V	
Gate-Source Voltage	V _{GS}	± 20		
Continuous Drain Current (T _J = 175 °C)	I _D	T _C = 25 °C	240 ^{a,e}	
		T _C = 70 °C	215	
		T _A = 25 °C	59 ^{b, c}	
		T _A = 70 °C	38 ^{b, c}	
Pulsed Drain Current	I _{DM}	900	A	
Avalanche Current Pulse	L = 0.1 mH	I _{AS}		220
Single Pulse Avalanche Energy		E _{AS}		910
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C	240 ^a	
		T _A = 25 °C	56 ^{b, c}	
Maximum Power Dissipation	P _D	T _C = 25 °C	370 ^a	
		T _C = 70 °C	237	
		T _A = 25 °C	52 ^{b, c}	
		T _A = 70 °C	36 ^{b, c}	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{b, d}	R _{thJA}	1.5	2.9	°C/W
Maximum Junction-to-Case	R _{thJC}	0.25	0.4	

Notes:

- a. Based on T_C = 25 °C.
- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 10 s.
- d. Calculated based on maximum junction temperature.
- e. Package limited.

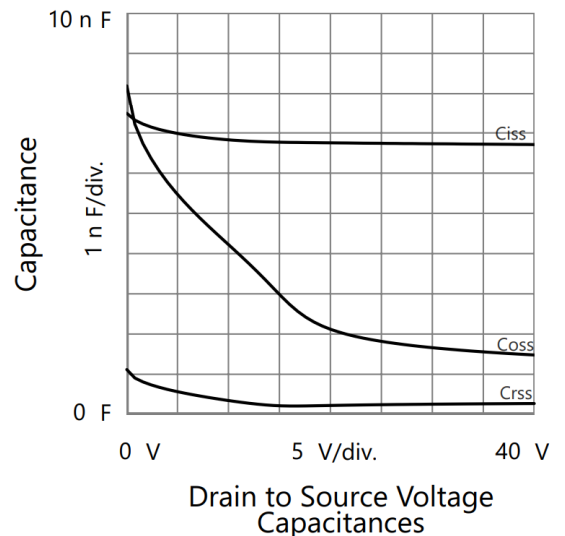
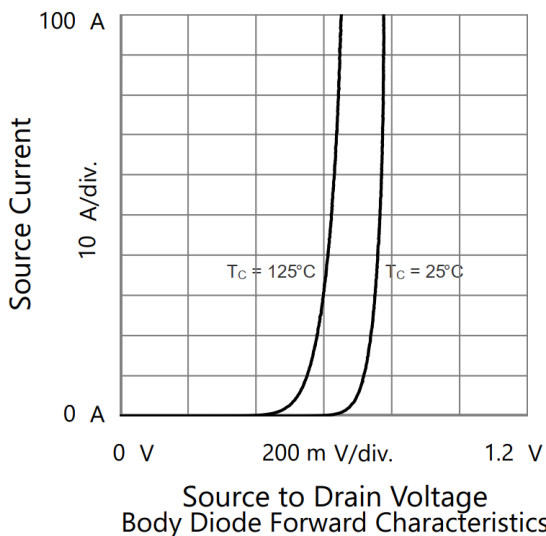
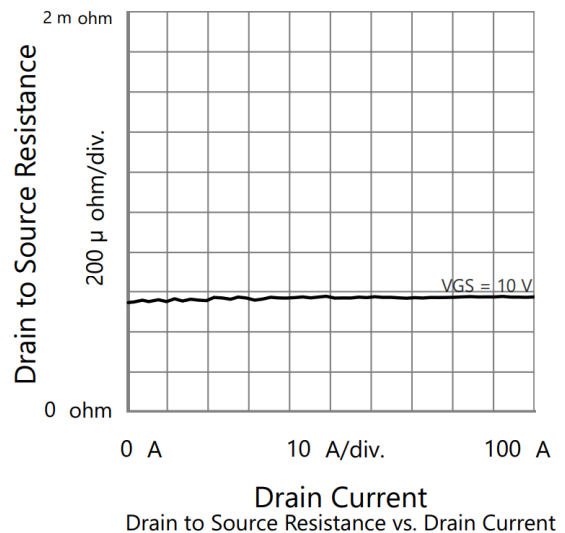
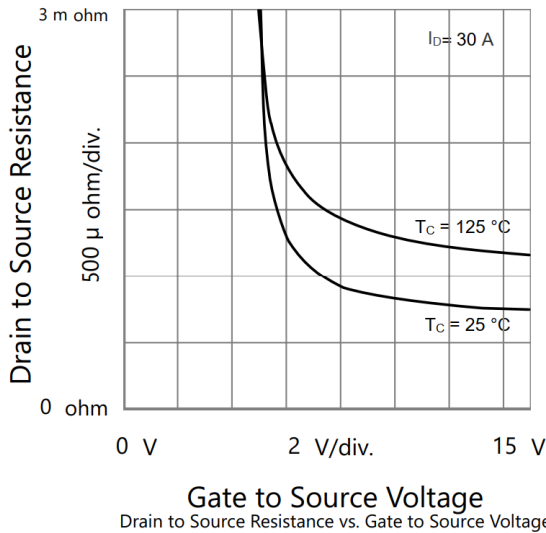
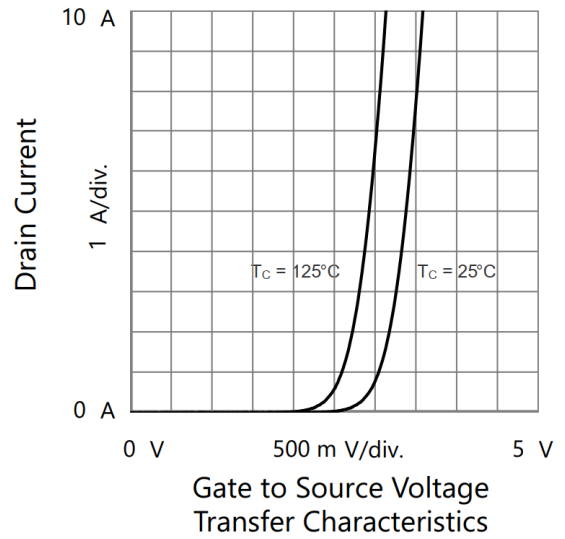
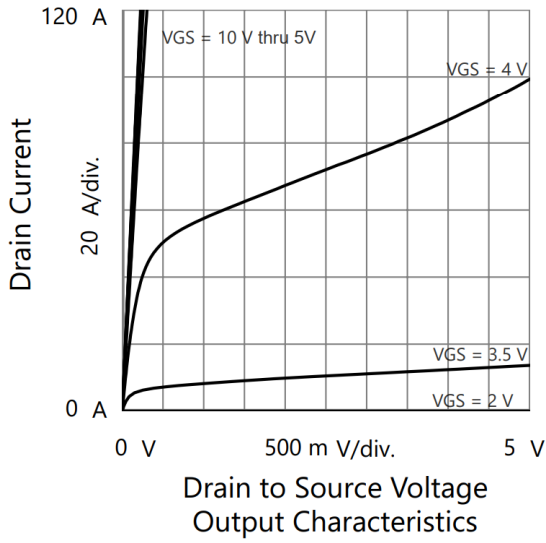
SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min .	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$	40			V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250\text{ }\mu\text{A}$		25		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 6.2		
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	1.5		3.5	V
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 40\text{ V}, V_{GS} = 0\text{ V}$			1	μA
		$V_{DS} = 32\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^\circ\text{C}$			10	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} \geq 5\text{ V}, V_{GS} = 10\text{ V}$	240			A
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 30\text{ A}$		0.58	0.8	m Ω
Forward Transconductance ^a	g_{fs}	$V_{DS} = 5\text{ V}, I_D = 30\text{ A}$		120		S
Dynamic^b						
Input Capacitance	C_{iss}	$V_{DS} = 20\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		6750		pF
Output Capacitance	C_{oss}			2120		
Reverse Transfer Capacitance	C_{rss}			190		
Total Gate Charge	Q_g	$V_{DS} = 20\text{ V}, V_{GS} = 10\text{ V}, I_D = 30\text{ A}$		97		nC
Gate-Source Charge	Q_{gs}			19		
Gate-Drain Charge	Q_{gd}			13		
Gate Resistance	R_g	$f = 1\text{ MHz}$		1.5		Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 15\text{ V}, R_L = 0.555\text{ }\Omega$ $I_D \cong 30\text{ A}, V_{GEN} = 10\text{ V}, R_g = 1\text{ }\Omega$		26		ns
Rise Time	t_r			10		
Turn-Off Delay Time	$t_{d(off)}$			65		
Fall Time	t_f			10		
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I_S	$T_C = 25\text{ }^\circ\text{C}$			240	A
Pulse Diode Forward Current ^a	I_{SM}				900	
Body Diode Voltage	V_{SD}	$I_S = 1\text{ A}$		0.6	1.2	V
Body Diode Reverse Recovery Time	t_{rr}	$I_F = 30\text{ A}, di/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^\circ\text{C}$		26		ns
Body Diode Reverse Recovery Charge	Q_{rr}			90		nC
Reverse Recovery Fall Time	t_a			27		ns
Reverse Recovery Rise Time	t_b			25		

Notes:

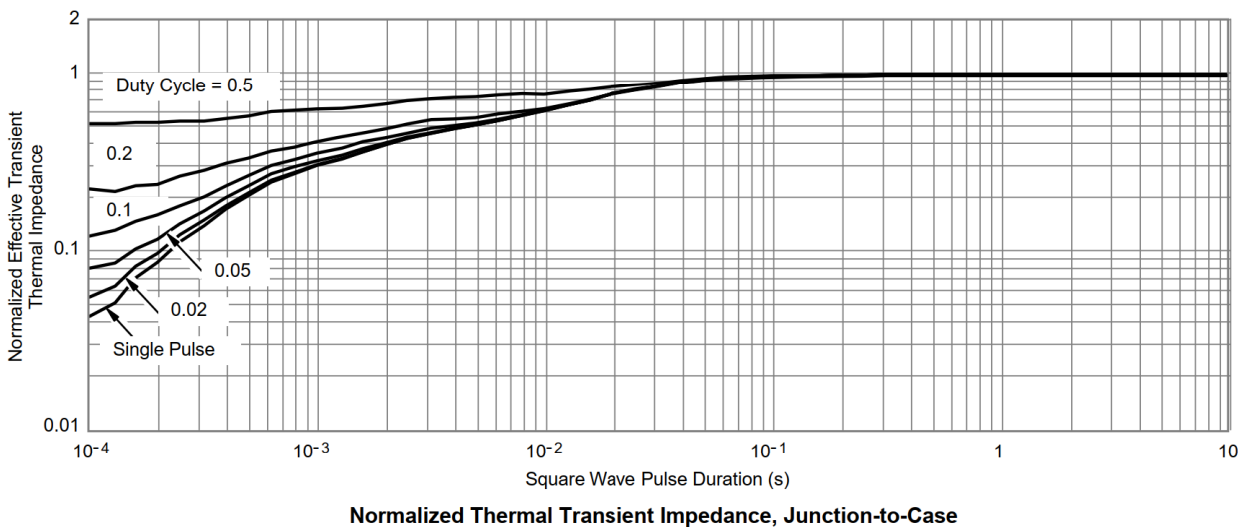
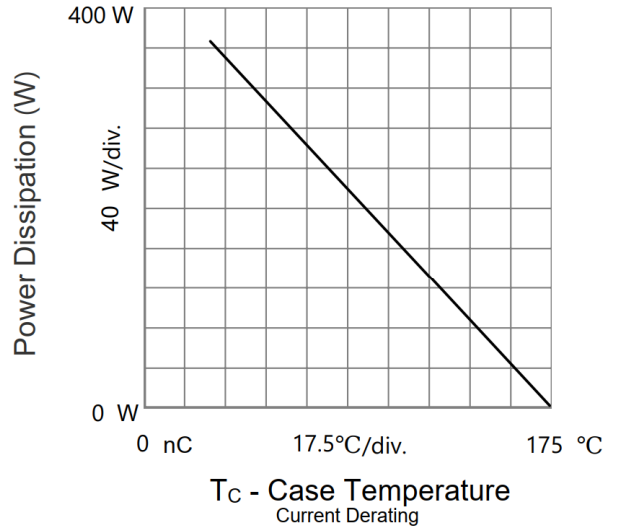
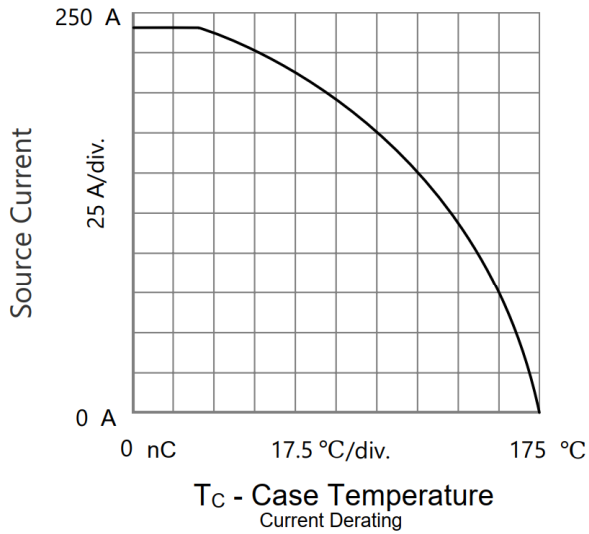
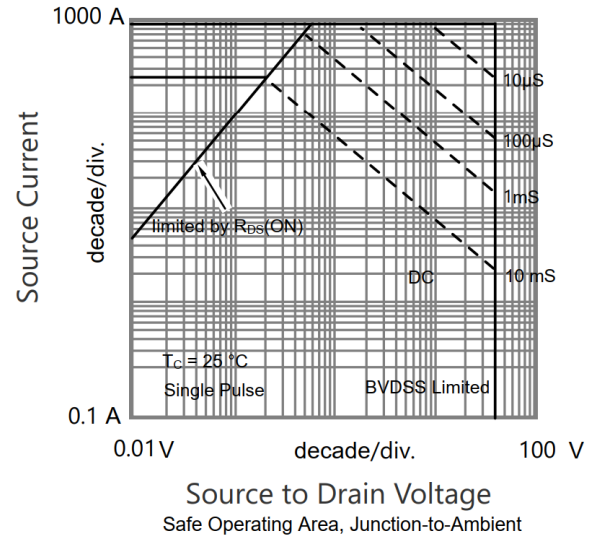
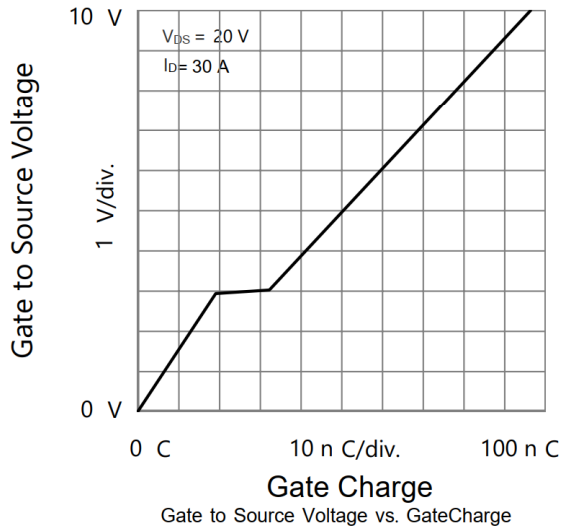
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

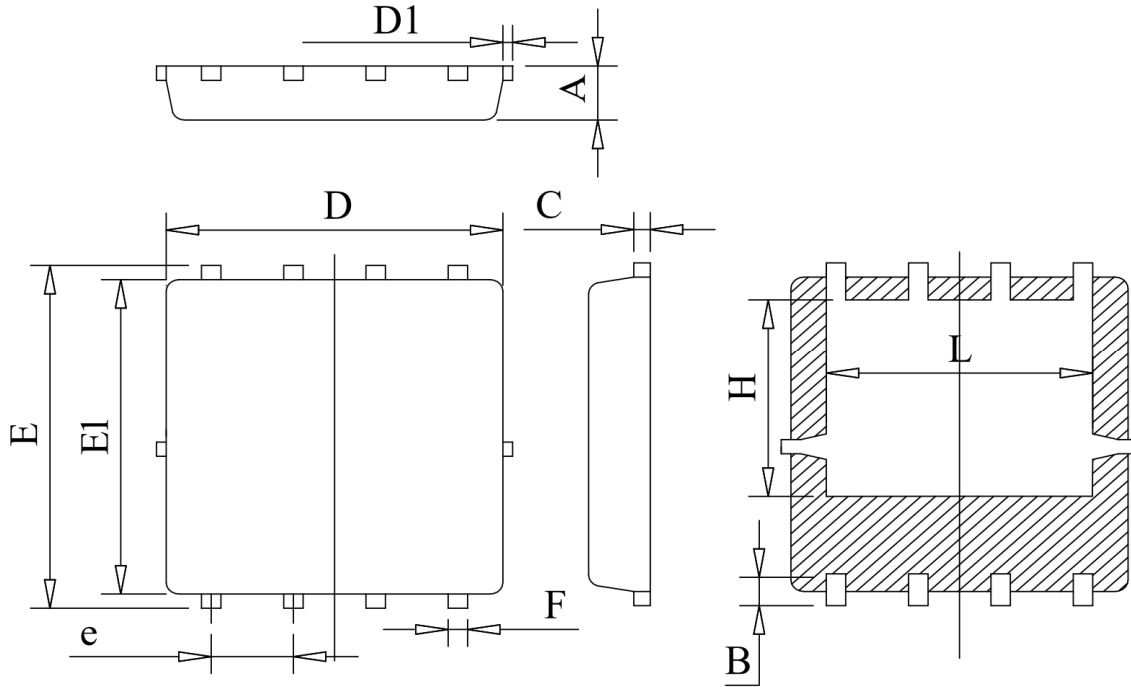
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



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DFN5X6-8L PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

Unit : mm

Symbol	Min	Typ	Max
A	0.78	0.95	1.12
B	0.45	0.58	0.78
C	0.18	0.254	0.36
D	4.70	5.20	5.45
D1			0.18
E	5.85	6.05	6.25
E1	5.38	5.55	5.98
e	1.15	1.27	1.40
F	0.18	0.30	0.52
H	3.25	3.47	3.70
L	3.75	4.00	4.25

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